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# Phase m easurem ents in A haronov-B ohm interferom eters 

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#### Abstract

In this paper we address $m$ easurem ents of the resonant quantum transm ission amplitude $t_{Q D}=$ i洧 $D \dot{j}^{i} Q D$ through a quantum $\operatorname{dot}(Q D)$, as function of the phinger gate voltage $V . M$ esoscopic solid state $A$ haronov $B$ ohm interferom eters (ABI) have been used to $m$ easure the \intrinsic" phase, QD, when the QD is placed on one of the paths. In a \closed" interferom eter, connected to two term inals, the electron current is conserved, and O nsager's relations require that the conductance $G$ through the $A B I$ is an even function of the $m$ agnetic $u x=h c=e$ threading the $A B I$ ring. Therefore, if one ts $G$ to $A+B \cos (+$ ) then only \jumps" between 0 and,$w$ th no relation to QD. Additional term inals open the A B I, break the O nsager relations and yield a non-trivial variation of with V.A fter review ing these topics, we use theoretical m odels to derive three results on this problem : (i) For the one-dim ensional leads, the relation $t_{Q D} J^{2} / \sin ^{2}(Q D)$ allows a direct $m$ easurem ent of $Q D$. (ii) In $m$ any cases, the $m$ easured $G$ in the closed ABI can be used to extract both tod jand QD. (iii) For open ABI's, depends on the details of the opening. W e present quantitative criteria (which can be tested experim entally) for to be equal to the desired $Q D$ : the \lossy" channels near the $Q D$ should have both a sm all transm ission and a sm all re ection.


K ey $W$ ords: interference in nanostructures, A haronov-B ohm interferom eter, quantum dots, resonant transm ission.

## 1. Introduction and $R$ eview of Experim ents

$R$ ecent advances in the fabrication of nanom eter scale electronic devioes raised $m u c h$ interest in the quantum $m$ echanics ofquantum dots ( Q D s), which represent arti cialatom sw ith experim entally controllable properties [1,2]. A exible m ethod to construct m esoscopic QD $s$ is based on the two dim ensional electron gas (2D EG), which exists in the planar interface betw een an insulator and a sem iconductor, $w$ ith a m etallic layer under the insulator. M etallic electrodes, which are placed above the sem iconducting layer, create potentials on the 2 DEG which restrict the electrons to m ove only in parts of the plane [3]. The sim plest $Q D$ geom etry consists of a sm all bounded region, which can bind electrons. This QD is connected via two one-dim ensional (1D ) im etallic' leads to electron reservoirs. T he coupling ofeach lead to the Q D is controlled by a potentialbarrier. T he potential on the Q D itself, called the plunger gate voltage', V , determ ines the attraction of electrons to the QD, and thus also the energies of electronic bound states on the QD. The sim plest experim ents then $m$ easure the conductance $G$ through the $Q D$, as function of $V$. The m easured $G$ show s peaks whenever the Ferm ienergy $F$ of the electrons crosses a bound state on the $Q D . Q$ uantum $m$ echanically, we should think of an electronic wave, $e^{\text {ikx }}$, hitting the QD from the left. O ne then ends up $w$ ith a re ected wave, $r_{Q D} e^{i k x}$ and a transm itted $w a v e, t_{Q D} e^{i k x}$. The quantum inform ation on the resonant
tunneling through the $Q D$ is contained in the com plex transm ission am plitude, $t_{Q D}=\sum_{i}^{P} \overline{T_{Q D}} e^{i} Q_{D}$. It is thus of great interest to $m$ easure both the $m$ agnitude $T_{Q D}$ and the phase $Q D$, and study their dependence on $v$.

Theoretically, the phase QD is particularly interesting, given its relation to the additional electron occupation in the system via the Friedel sum rule [4,5]. This phase is also predicted to exhibit interesting behavior e.g. near a K ondo-like resonance [6]. For a sim ple model of non-interacting electrons with several equid istant bound state energies, theory yields the $m$ agnitude and the phase as show $n$ in $F$ ig. 1 (see below for details): $T_{Q D}$ exhibits resonances at the bound state energies, while $Q D$ exhibits an interesting variation between 0 and , grow ing gradually through each resonance, and dropping sharply between consecutive resonances (here and in all follow ing graphs, we set and at zero far below the resonances). The resonant dependence of $T_{Q D}$ on $V$ has been con $m$ ed by $m$ any experin ents $[1,2]$, which $m$ easure the conductance and take advantage of the Landauer form ula $[7], G=\frac{2 e^{2}}{h} T_{Q D}$. How ever, the experim entalm easurem ent of $Q D$ has only becom e accessible since 1995 [8, 9], using the A haronov $B$ ohm (AB) interferom eter [10]. As explained below, $m$ any experim ents $m$ easure a phase (which we call) which 'oscillates' betw een 0 and . $H$ ow ever, the relation of these $m$ easured values to the desired $Q D$ is not trivial. $T$ his relation is one of the $m$ ain topics of this review.


$F$ igure 1. Theoreticaltransm ission $T_{Q D}$ and \intrinsic" phase QD for $N=4$ states on theQ $D$, $w$ ith $\backslash g a p " U=20 J$, versus the gate voltage $V$ (in units of J). See Sec. 2 for details.

The sim plest $m$ ethod to $m$ easure the phase of a wave is based on the two-slit interferom eter [11]. In this geom etry, a coherent electron beam is split betw een two paths, going through two slits, and one m easures the distribution of electrons absorbed on a screen behind the two slits. A ssum ing that each electron goes through one of the slits only once, w thout any re ection from the slits or from the screen, and assum ing com plete coherence, the distribution of electrons on the screen is given by $T=f f$, where $t=t_{1}+t_{2}$ is the sum of the (oom plex) am plitudes of the waves which went via the two slits.

In the two-slit $A B$ interferom eter, one adds am agnetic $u x$ in the area surrounded by the two electron ic paths. Such a ux creates a non-zero electrom agnetic vector potential, A, even where the ux vanishes. W ith an appropriate choice of gauge, the kinetic energy of the electron becom es $(p+e A=C)^{2}=(2 \mathrm{~m})$, where $p$ is the electron $m$ om entum. As a result, then $w$ ave function of the free electron which $m$ oves from $r_{1}$ to $r_{2}$ obtains an additional phase $12=(e=h c) r_{r_{1}} A(r) d r$, where the integration is along the path of the electron. A haronov and Bohm [12] used this fact to predict that such a ux between the two paths would
add a di erence $=e=h c$ betw een the phases of the $w$ ave functions in the tw o branches of the ring, yielding

$$
\begin{equation*}
t=t_{1} e^{i}+t_{2}: \tag{1}
\end{equation*}
$$

(G auge invariance allow s one to attach the AB phase to eitherbranch). W riting $t_{i}=t_{i} \dot{j}^{i}{ }^{i}$, one thus has

$$
\begin{equation*}
T=A+B \cos (+) ; \tag{2}
\end{equation*}
$$

where $=1 \quad 2$. A ssum ing that one of the phases can be varied experim entally (e.g. by placing a Q D on one path and changing its plunger gate voltage $V$ ), this 2 -slit form ula' can then be used to deduce the dependence of the phase on extemalparam eters (e.g. V).

Experim ents using tw o-slit geom etries for electron interference, using electron microscopes, which conm ed the AB e ect, have been described in detail by Tonom ura [13]. In the present paper we concentrate on experim ents which use $m$ esoscopic devices. A coherent ow of electrons requires that the $m$ ean free path L, , over which scattering destroys the electron's phase, should be larger that the sam ple size. This can be achieved by going to low tem peratures and by using sm all sam ples. The rst con $m$ ation ofthe ABeect in a $m$ esoscopic system $w$ as done by $W$ ebb et al. [14]. T hey used a sm allm etal ring, which was connected (at tw o opposite points) to electron reservoirs through tw o leads. Indeed, the conductance of the ring show ed a periodic dependence on the $m$ agnetic ux inside the ring,, w ith a leading Fourier com ponent at the period $\mathrm{e}=\mathrm{hc}$, as expected. H ow ever, th is experim ent did not allow a variation of the relative phase, nor a detailed test of the two-slit form ula (2); speci cally, the Fourier analysis contained also higher harm onics.

The rst attem pt to vary the phase of the wave on one of the paths was done by Yacoby et al. [8]. They used the sem iconducting QD system described above, in which the electrons were also allowed to go via a reference' path, parallel to the path containing the QD (see Fig. 2a). A gain, the m easured conductance was periodic in , and the detailed dependence of $G$ on varied w ith the plunger gate voltage on the $Q D$, V. Far aw ay from a resonance, this conductance could be tted to Eq. (2). H ow ever, closer to a resonance the data seem to require $m$ ore harm onics in , e.g. of the form

$$
\begin{equation*}
T=A+B \cos (+)+C \cos (2+)+::: ; \tag{3}
\end{equation*}
$$

w ith the conventions B; C $>0$. Sunprisingly, the tted phase did not vary continuously $w$ ith $V$ (as would be implied from the $2-s$ lit scenario and Eq. (2)). Instead, rem ained xed between resonances, w ith only discrete jumpsby + (near a resonance) or by (betw een resonances). These discrete jum ps are de nitely di erent from the behavior of the intrinsic phase $Q D$, as shown e.g. in $F i g .1$. Therefore, these experim ents cannot be used for direct $m$ easurem ents of $Q D$, using Eq. (2) or Eq. (3).
$T$ he reason for this discrepancy was soon understood. B oth the experim ents by $W$ ebb et al and by Y acoby et al. were done on closed' interferom eters, which di er signi cantly from the two-slit geom etry. Unlike the latter, the form er require $m$ any re ections of the electron waves from the Yorks' connecting the ring w ith the leads; there is no way to w rite a 33 unitary $m$ atrix, which contains no re ections in two of the three channels. Each such re ection adds a term to the interference sum of am plitudes, and m odi es the sim ple tw o-slit form ula. In fact, it was already show n by O nsager [15,16] that unitarity (conservation of current) and tim e reversal sym m etry im ply that $G()=G(\quad)$, and therefore (as well as etc.) m ustbe equal to zero or , as observed by Y acoby et al. G iven the $O$ nsager relation, it is clear that the data from the closed interferom eter should not be analyzed using the two-slit form ula (2). H ow ever, we show below that there exists a m ore com plicated form ula, which contains the $m$ any re ections from the Yorks', and that this form ula can be used to extract the phase QD from the closed interferom eter data [17].

Later experim ents [9] opened the interferom eter, using the six-tem inalcon guration show $n$ schem atically in Fig. 2 (b); the additionalleads allow losses ofelectronic current, thus breaking unitarity. Indeed, tting the conductance to Eq. (2) yielded a phase which was qualitatively sim ilar to the calculated $Q D$, as shown in Fig. 1: a gradualincrease through each resonance (accom panied by peaks in the am plitudes A and B), and a sharp \phase lapse" back to zero between resonances (accom panied by zeroes in B). These experim ental results led to m uch theoreticaldiscussion. Som e of this $[18,19]$ em phasized the non-triviale ects of the ring itself on the $m$ easured results, even for the closed case. O ther theoretical papers $[20,21,22,23,24,25,26]$ assum ed that the $m$ easured represents the correct $Q D$, and discussed the possible origins of the observed features, e.g. the \phase lapse" and the sim ilarity betw een the data at $m$ any resonances. H ow ever, until


Figure 2. M odel for the A B interferom eter: (a) C losed tw o-tem inal case, (b) Schem atic picture of the six-term inal open interferom eter, (c) M odel for the open interferom eter.
recently there existed no quantitative com parison of the m easured $w$ ith the intrinsic ${ }^{\prime}$ QD. In fact, as explained below, it tums out that depends on the strength of the coupling to the open channels: when this coupling vanishes (in the closed' lim it), jum psbetw een zero and. A sthe coupling increases, the increase of near a resonance becom es less steep, $w$ th a slope that decreases $w$ ith increasing coupling [27]. Thus, it is not enough to open the interferom eter; one also needs to choose speci cmethods of opening, and to tune the relevant param eters! Below we present a theoreticalm odel, aim ed to im itate the experim ental setups of Fig. 2 (a) and (b) [28]. It has been found that the two-slit conditions can be im itated if one replaces each lossy channel in $F$ ig. 2 (b) by $m$ any such channels, as illustrated in $F$ ig. 2 (c). Figure 3 show s exam ples of our m odel calculations for A ; B ; C and versus V. Q ualitatively, these plots look sim ilar to those found experim entally $[8,9]$. H ow ever, as discussed below, the quantitative results for the open interferom eters depend on details of the opening.

## 2. M odels for the Q D

W e dem onstrate our results for a sim ple lattice $m$ odel, in which the dot is represented by a single site \D " (located at the origin), on a 1D tight binding chain [29]. All the on-site energies are zero, except $D$ on the Q D. D can be varied experim entally by the plunger gate voltage V. A susual for such m odels, electronelectron interactions are included only via an on-site $H$ ubbard interaction $U$ on the $Q D . T$ he hopping $m$ atrix elem ents $J_{i ; i+1}$ on the chain are all equal to $J$, except on the bonds connected to the $Q D$, where they are $J_{1 ; D}=J_{L}$ and $J_{D ; 1}=J_{R}$. Our Ham iltonian is thus given by

$$
\begin{equation*}
H_{0}=X \quad D d^{y} d+\frac{U}{2} n_{d} n_{d} \quad J_{i \neq 1 ; 0}^{X}\left[C_{(i+1)}^{y} C_{i}+h: c:\right] \quad\left[U_{1} d^{y} C_{1}+J_{R} C_{1}^{y} d+h: c:\right] ; \tag{4}
\end{equation*}
$$

$w$ here $c_{i}^{y}$ creates an electron ( $w$ ith spin ) on site i. For the unperturbed chain ( $w$ ith $D=0, U=0$ and $J_{\mathrm{L}}=J_{\mathrm{R}}=J$ ), one has sim ple wave eigenstates, w ith w ave vectors k and eigenenergies $\mathrm{k}=2 \mathrm{~J}$ coska ( a is the lattice constant). The operators on the dot, $d$ and $d^{y}$, anti-commute with $c_{i} ; c_{i}^{y} . A l s o, n_{d}=d^{y} d$, and -

A dapting the results of $R$ ef. [29], the transm ission am plitude through the $Q D$ at zero tem perature is

$F$ igure 3. A; B; C and fortransm ission through the closed A B ring (upper left), and for the open interferom eter w ith $J_{\mathrm{x}}=: 15 \mathrm{~J}$ (upper right) and $J_{\mathrm{x}}=: 9 \mathrm{~J} ; 1: 5 \mathrm{~J}$ (low er left, right). T he dashed line show s the exact intrinsic phase $Q D$, from Fig. 1. For details see Sec. 4 below.
given by

$$
\begin{equation*}
t_{Q D}=i_{D} \sin Q D e^{i} Q D \quad 2 i \sin k j \mathcal{M}_{E} J_{R} g_{D}(k)=J ; \tag{5}
\end{equation*}
$$

w th the QD asymmetry factor $D=2 J_{L} J_{R}=\left(J_{L}^{2}+J_{R}^{2}\right)$ and the \intrinsic" $G$ reen function on the $Q D$, $g_{D}(k)=1=[k \quad D \quad D(k)]$. Here, $D(k)$ is the selfenergy on the $Q D$, which contains contributions from the leads, $D$;ext $=e^{j k j a}\left(J_{L}^{2}+J_{R}^{2}\right)=J$ (which exists also for the non-interacting case [27]), and from the electron-electron interactions on the QD itself, $D$;int (!) (which vanishes when $U=0$ ). As $D V$ increases, QD grow sgradually from zero (farbelow the resonanœe), through $=2$ (at the resonance), tow ards (far above the resonance).
Interestingly, for this one-dim ensionalm odel, norm alizing the $m$ easured

$$
\begin{equation*}
T_{Q D}=t_{Q D} J={ }_{D}^{2} \sin ^{2}(Q D) \tag{6}
\end{equation*}
$$

by its ( $V$-independent) $m$ axim um $m a x\left[T_{Q D}\right] \quad{ }_{D}^{2}$ yields the value of $Q D$. Assum ing coherence, thism ethod form easuring $Q D$ directly from $T_{Q D}$ elim inates the need for any complicated interferom etry! (H ow ever, interferom etry is still im portant, since it ensures coherence. Interestingly, this conclusion holds for any $B$ reit-w igner-like resonance, $w$ th an energy-independent $w$ idth. It also holds for a multi-level Q D, w ith $m$ any resonances). In the next section we discuss ways of extracting $Q D$ indirectly, from the closed $A B$ interferom eter $m$ easurem ents. Com paring results from $\sin ^{2}(Q D)=T_{Q D}={ }_{D}^{2} \quad T_{Q D}=m a x\left[T_{Q D}\right]$, from the closed interferom eter [17] and from the open one [28] (all w ith the sam e Q D) should serve as consistency checks for this conclusion.

A s explained above, at $T=0$ the intrinsic' transm ission am plitude and phase are directly related to the bare' $G$ reen function $g_{D}$ at the Ferm i energy, $F$, which is equal to $k$. Explicit calculations of this G reen function, in the presence of interactions, are non trivial. A though som e of the results below w ill be given in term s of the full $G$ reen function, it is often useful to use simple expressions to ilhustrate speci c points. For such purposes, in som e of the explicit calculations below we follow m any earlier calculations
$[18,26,30,31,32]$, and ignore the interactions. For $U=0$, we end up $w$ ith a sim ple single-electron tightbinding model. In this case, the Schrodinger wave equation is written as (E i) ${ }_{i}=j_{j} J_{i j} \quad$, where the sum is over nearest neighbors of $i$. The scattering solution for a wave com ing from the left, with wave vector $k$ and energy $E=2 J$ coska, is described by $\underset{m}{L}=e^{i k a m}+r e^{i k a m}$ on the left, and by ${ }_{m}^{R}=$ te ${ }^{i k a m}$ on the right. The calculation of the transm ission and re ection am plitudes, $t$ and $r$, then am ounts to solving a nite set of linear equations for the $w$ ave functions inside the scatterer.

Sim ilar linear equations arise for single electron scattering from more com plex geom etries, like those shown in $F$ ig. 2. In each such calculation, we have a scattering elem ent (e.g. the hing') connected to two one-dim ensional (1D) leads, which have $J_{i ; i+1}=J ; i=0$. All the explicit graphs presented in the paper are based on the extraction of the total transm ission am plitude $t$ from such equations.

A s discussed above, in $m$ any cases one is interested in dots which have m ore than one resonance. W thout interactions, it is easy to generalize the above tight-binding $m$ odel to a Q D w ith $m$ any discrete energy levels. $T$ his is done by a set of sm aller dots, each containing a single resonant state, $w$ ith energy $f_{D}=E_{R}(n)$; $n=$ $1 ;::: ; N \mathrm{~g}$. T his m odel is show n in Fig .4 for $\mathrm{N}=4$. Each such state (or sm all dot) is connected to its left and right nearest neighbors on the leads via bonds $w$ ith hopping amplitudes $f J_{L}(n) ; J_{R}(n) ; n=1 ;:: ; N g$. $T$ he $Q D$ can thus be described by $N$ wave functions $n$, obeying $\left.\mathbb{E} \quad E_{R}(n)\right]_{n}=\Psi_{( }(n){ }_{0}^{L} \quad \Phi_{R}(n){ }_{0}^{R}$ (where we choose ${ }_{0}^{\mathrm{L}}=1+\mathrm{r} ;{ }_{0}^{\mathrm{R}}=\mathrm{t}$ ). The exact transm ission am plitude is easily found to be

$$
\begin{equation*}
\left.t_{Q D}=\frac{S_{L R} 2 i \sin k a}{\left(S_{L L}+e^{i k a}\right)\left(S_{R R}+e^{i k a}\right)} \operatorname{SG}_{L R}\right\}^{2} ; \tag{7}
\end{equation*}
$$

where

$$
\begin{equation*}
S_{X Y}=\frac{X}{n} \frac{J_{X}(n) J_{Y}(n)}{\left.J \mathbb{E} E_{R}(n)\right]} ; \quad X ; Y=L ; R \tag{8}
\end{equation*}
$$

represent \bare" $G$ reen's functions for sites $L$ and $R$ (in the previous notation, these were sites 1 and 1 on the chain).


Figure 4. M odel for a QD w ith four discrete energy levels.
Figure 1 was generated by Eq. (7), w ith equidistant bound state energies, $E_{R}(n)=V+U(n \quad 1)$. The \gap" U can be view ed as the H artree energy for an electron added to a QD which already has $n \quad 1$ other electrons [20], thus capturing som e aspects of the $C$ ou lom b blockade behavior of the scattered electron. $W$ e study $t_{D} D$ as fiunction of the energy $V$, which represents the plunger gate voltage on the $Q D$. In this gure and below, we choose ka $=2$, so that $E=0$ and the resonances of the transm ission, where $T_{Q D}=1$, occur exactly when $E_{R}(n)=E=0$, i.e. when $V=U(n \quad 1)$ [33]. Results are not sensitive to $k$ near the band center. $W$ e also use the sim ple sym $m$ etric case, $J_{L}(n)=J_{R}(n) \quad J$, and $m$ easure allenergies in units of $J$. A smentioned, this m odel reproduces the apparently observed behavior of $Q D$ : it grow ssm oothly from 0 to asE crosses $E_{R}(n)$, and exhibits a sharp \phase lapse" from to 0 betw een neighboring resonances, at points $w$ here $T_{Q D}=0$. These latter points, associated $w$ ith zeroes of $S_{L R}$, represent Fano-like destructive interference betw een the states on the Q D $[35,22,23,34,36]$.

In fact, Eq. (7) gives an excellent approxim ant for the scattering through a general Q D, w ith several com peting resonances. In Fig. 5 we present results for the transm ission through such a QD, with an
appropriate (non-sym m etric) choige of the param eters $f E_{R}(n)$; $J_{L}(n)$ and $J_{R}(n) g$, and $N=5$. This gure reproduces all the experim ental features observed by $G$ ores et al. [37], in scattering from a single electron transistor. C learly, our Eq. (7) gives a m uch better description of the data, w ith less param eters, com pared to the sum of individual non-sym $m$ etric Fano expressions [35] used in Ref. [37] to $t$ the experim ents.


Figure 5. C onductance versus gate voltage for a m odel of a single electron transistor, based on Eq. (7).
$M$ any earlier theoretical (e.g. [20]) and experim ental (e.g. [9]) papers approxim ated $t$ by a sum of the single resonance B reit-W igner-like (BW ) expressions [38],

$$
t_{Q D} \quad \begin{gather*}
\left.\quad \frac{e^{2 i k a} 2 i \sin k a J_{L}(n) J_{R}(n)}{E} \quad E_{R}(n)+e^{i k a}\left[j_{L}(n)\right\}^{2}+\dot{j} J_{R}(n) \mathcal{J}^{2}\right]=J \tag{9}
\end{gather*}:
$$

Each term here has the form of Eq. (5), apart from a trivialoverall phase factor $e^{2 \mathrm{ika} \text {. A though this form }}$ gives an excellent approxim ation for $t_{Q D}$ near each resonance, it com pletely $m$ isses the Fano-like zeroes and the \phase lapses" betw een resonances. This happens because the approxim ation $m$ oves the zeroes o the real energy axis [34]. As a result, the approxim ate $Q D$ never reaches 0 or, and exhibits a sm ooth decrease from a m axim um to a m inim um near the correct \phase lapse" values of V. Since our aim here is to check on accurate $m$ easurem ents of the \intrinsic" phase, for a broad range of the param eters, and since the phase lapse has been a topic of m uch recent discussion $[20,21,22,23,24,25,26]$, we prefer to use the exact solutions everyw here. This is particularly im portant since typically, available experim ental data [9] show quite broad resonances, so that the BW approxim ation is bound to failbetween them.

We em phasize again: in spite of the close sim ilarity of our \intrinsic" transm ission results with the experim ents, the purpose of this paper is not to relate the calculated $t_{D} D$ to the experim ental system $s . T$ his would require a justi cation for our choice of the sam e $J_{L}(n)$ 's and $J_{R}(n)$ 's for all the resonances, whidh goes beyond the scope of the present paper. R ather, we aim to check when the A B interferom eter reproduces the \input" behavior of the QD, by yielding $=Q D$ for all $V$. If this fails for our sim ple $m$ odel then it would surely fail in the $m$ ore com plicated cases, where electron-electron interactions (beyond our sim ple H artree approxim ation) becom e im portant [39].

## 3. M odel for the closed A B interferom eter

$W$ e next place the above $Q D$ on the upper branch of the closed $A B$ interferom eter, as show $n$ in $F$ ig. 2 (a). In the context of our tight binding $m$ odel, this translates into the $m$ odel show $n$ in $F$ ig. 6: in addition to the path through the QD, we add a reference' path, which connects the left and right leads to the site ref' via $m$ atrix elem ents $I_{L}$ and $I_{R}$. Ignoring electron interactions on this path, the new $H$ am iltonian becom es

$$
\begin{equation*}
\mathrm{H}=\mathrm{H}_{0}+{ }^{\mathrm{X}} \quad 0_{0}^{\mathrm{y}} \mathrm{C}_{0} \quad \mathrm{E}\left[\mathrm{C}_{1}^{\mathrm{y}} \mathrm{C}_{0}+\mathrm{h}: \mathrm{C}:\right] \quad \mathrm{E}\left[\mathrm{c}_{0}^{\mathrm{y}} \mathrm{C}_{1}+\mathrm{h}: \mathrm{C}:\right]: \tag{10}
\end{equation*}
$$

T he reference site energy o can be varied experim entally by an appropriately chosen gate voltage, which we denote by $V_{0}$. A dding a $m$ agnetic ux inside the $A B$ ring now requires adding a phase anyw here around the ring. $U$ sing gauge invariance, $w e$ do this by the replacem ent $J_{R}!J_{R} e^{i}$.

$F$ igure 6. M odel for the closed AB interferom eter.

In principle, one can now start from the exact relation of Eq . (5), and add the e ects of the reference' path perturbatively, as a power series in $I_{L}$ and $I_{R}$. A $m$ ore general approach uses the standard relation betw een the 22 scattering $m$ atrix $\mathrm{T}_{\mathrm{kk}} 0$ and them atrix of retarded single-particle G reen fiunctions, $\mathrm{G}_{\mathrm{kk}}{ }^{0}(!)=$
 equation-ofm otion ( EOM ) m ethod [6] is then used to express (! $\left.{ }_{\mathrm{k}}\right) \mathrm{G}_{\mathrm{kk}^{0}}(!)$ and (! $\left.\mathrm{k}_{\mathrm{k}}\right) \mathrm{G}_{\mathrm{kd}}(!)$ as linear com binations of each other and of $G_{D}$ (!), allow ing us to express each of them (and thus also $t / T_{j k j ; j j}$ ) in term $s$ of the $G$ reen function on the dot, $G_{D}(!)$. Since we do not use an explicit solution for $G_{D}(!)$ itself, we don't need to dealw ith the higher order correlation functions (due to $U$ ), which appear in its EOM. T he result of these procedures has the form [17]

$$
\begin{equation*}
t=A_{D} t_{D D} e^{i}+A_{B} t_{B} ; \tag{11}
\end{equation*}
$$

where $A_{D}=g_{B}(k \quad 0) G_{D}(k)=g_{D}(k)$ and $A_{B}=1+G_{D}(k) \quad \operatorname{ext}(k)$. Here, $G_{D}(!)=1=[!\quad \quad(!)]$ is the fully \dressed" G reen function on the $Q D$, $w$ ith the dressed selfenergy $=$ int + ext. Both term $s$ in di er from their counterparts in the \intrinsic" D, by contributions due to the reference path. A lso,

$$
\begin{equation*}
t_{B}=\quad i_{B} \sin { }_{B} e^{i} B=2 i \sin k j L_{L} I_{R} g_{B}=J \tag{12}
\end{equation*}
$$

is the transm ission amplinde of the \background", or \reference", path (when $J_{L}=J_{R}=0$, or $j_{D} j$ ! 1 ), $w$ ith the bare reference site $G$ reen function $g_{B}=1=\left[k \quad 0+e^{i j j}\left(I_{L}^{2}+I_{R}^{2}\right)=J\right]$, and the asym $m$ etry factor $B=2 I_{L} I_{R}=\left(I_{L}^{2}+I_{R}^{2}\right)$.

Equation (11) looks like the two-slit form ula, Eq. (1). H ow ever, each of the term $s$ is now renorm alized: $A_{D}$ contains all the additional processes in which the electron $\backslash v i s i t s "$ the reference site $\left(A_{D}=1 \mathrm{when}\right.$ $I_{L}=I_{R}=0$, or when $j o j!1$ ), and $A_{B}$ contains the corrections to $t_{B}$ due to \visits" on the dot. $W e$ now discuss the -dependence of $T \quad t \xi$, in connection $w$ th the $O$ nsager relations and $w$ th the possible indirect extraction of QD.

W e rst note that both parts in ( k ) are even in , due to additive contributions (w ith equalam plitudes) from clockw ise and counterclockw ise $m$ otions of the electron around the ring (see e.g. Refs. [10, 27, 30, 40]). In order that $T$ also depends only on cos , as required by the O nsager relations, the ratio $K$ $A_{B} t_{B}=\left(A_{D} t_{Q D}\right) \quad x\left[G_{D}(k)^{1}+\operatorname{ext}(k)\right]$, w ith the real coe cient $x=I_{L} I_{R}=\left[J_{L} J_{R}(k \quad 0)\right]$, $m$ ust be real, i.e.

$$
\begin{equation*}
=\left[G_{D}(k)^{1}+\operatorname{ext}(k)\right]=\operatorname{int} 0: \tag{13}
\end{equation*}
$$

$T$ he sam e relation follow sfrom the unitarity of the 22 scattering $m$ atrix of the ring. $T$ his relation already appeared for the special case of single im purity scattering, in connection $w$ ith the Friedel sum rule [5], and was implicitly contained in Eq. (5), where $=\mathrm{D}$; int $=0$ [29]. Equation (13) implies that (at $T=0$ and $!=k$ ) the interaction selfenergy int $(k)$ is real, and therefore the width of the resonance, $=G_{D}(k)^{1}$, is fiully determ ined by the non-interacting self-energy $=\operatorname{ext}(\mathrm{k})$.

Since ext (! ) depends only on the (non-interacting) tight-binding term $s$, it is easy to calculate it explicitly. We nd ext $(\mathrm{k})=\mathrm{D}$;ext $(\mathrm{k})+\quad$ ext, where

$$
\begin{equation*}
\text { ext }=e^{2 i j k j} g_{B}\left(J_{L}^{2} I_{L}^{2}+J_{R}^{2} I_{R}^{2}+2 J_{L} J_{R} I_{L} I_{R} \cos \right)=J^{2}: \tag{14}
\end{equation*}
$$

The term proportionalto cos com es from the electron clock-and counterclockw isem otion around the AB \ring". Sim ilarly, one can write $\operatorname{int}(k)=D_{\text {;int }}(k)+\quad \operatorname{int}$, and thus $G_{D}(k)^{1}=g_{D}(k)^{1} \quad$, with $=\quad$ ext + int. Hence, $t=A_{D} t_{D}\left(e^{i}+K\right)$. Writing also $A_{D}=C=\left[\begin{array}{lll}1 & G(k)\end{array}\right]$, with $C=(k \quad 0) g_{B}$, we nd

$$
\begin{equation*}
T=j \mathrm{~J}^{2} \mathrm{~T}_{\mathrm{D}} \frac{1+\mathrm{K}^{2}+2 \mathrm{~K} \cos }{12<[g]+\dot{g_{D}} \dot{j}^{2}}: \tag{15}
\end{equation*}
$$

A though the num erator in Eq. (15) looks like the two-slit Eq. (1), with $=0$ or (depending on signK ), the new physics is contained in the denom inator \{ which becom es im portant in the vicinity of a resonance. The central term in this denom inator depends explicitly on the phase of the com plex num ber $g_{D}$. Since this num ber is directly related to $t_{Q D}$, via Eq. (5), one may expect to extract $Q D$ from a $t$ to Eq. (15), taking advantage of the dependence of the denom inator on cos. Physically, this dependence originates from the in nite sum over electron pathswhich circulate the AB ring. $R$ ef. [17] contains a detailed discussion of the conditions for such an extraction. Generally, this is not trivial, as one needs the detailed dependence of on cos and on the various param eters. W e have presented this dependence for ext, but not for int.

The extraction of $Q D$ becom es easy when one $m$ ay neglect int. The simplest case for this is for single-electron scattering, when int $=0$. Interactions (i.e. U 0) are also negligible for a relatively open dot, $w$ th $s m$ all barriers at its contacts $w$ th the leads [41]. A nother e ectively single-electron scattering case arises near a C oulom b blockade resonance, when the e ect of interactions can sim ply be absorbed into a H artree-like shiff, $D+$ int ! $\quad+N U$, if one assum es that $N$ depends sm oothly on the number of electrons on the QD, and not on [40]. If onem ay neglect int, then ext is given in Eq. (14). U sing also Eqs. (5) and (12), we nd

$$
\begin{equation*}
T=\operatorname{c}^{\rho} \mathrm{T}_{Q D} \frac{1+\mathrm{K}^{2}+2 \mathrm{~K} \cos }{1+2 \mathrm{P}(\mathrm{z}+\cos )+Q(\mathrm{z}+\cos )^{2}} ; \tag{16}
\end{equation*}
$$

where $z=\left(J_{L}^{2} I_{L}^{2}+J_{R}^{2} I_{R}^{2}\right)=\left(2 J_{L} J_{R} I_{L} I_{R}\right), P=\left\langle\left[v t_{B} t_{Q D}\right], Q=j t_{B} f_{Q D} T_{Q}\right.$, and $V=e^{2 i j k j}=\left(2 \sin ^{2} j k j\right)$ depends only on the Ferm iwavevector $k$, independent of any detail of the interferom eter. A 5-param eter $t$ to the explicit -dependence in Eq. (16) for given values of $V$ and $V_{0}$ then yields $\mathcal{J} \frac{f}{}{ }^{f} T_{Q D} ; K ; z ; P$ and $Q$, and thus $\cos (Q D+B+2 j \dot{j})=P=\bar{Q}$, from which one can extract the $V$-dependence of $Q D$. The sam eV-dependence of $Q D$ is also contained in $K /(c o t Q D+\cot j \dot{j})$ ). As discussed after Eq. (5), our $m$ odel also im plies that $T_{Q D}=\frac{2}{D} \sin ^{2}(\mathrm{D})$. Since the $V$-dependence of $T_{Q D}$ can also be extracted from the tted values of either $f f^{f} T_{Q D}$ or $Q$, we end up with several consistency checks for the determ ination of $Q D$. Additional checks arise from direct $m$ easurem ents of $T_{Q D}$ and $T_{B}=f_{B} f$, by taking the lim its $j V_{0} j=j o j!1$ or $j j_{j}=j_{D} j!1$.

The LHS frame in $F$ ig. 7 show $s$ an exam ple of the $V$-and -dependence of $T$ for this lim it (no interactions), with ka $=2$ and $J_{\mathrm{L}}=J_{\mathrm{R}}=\mathrm{I}_{\mathrm{L}}=\mathrm{I}_{\mathrm{R}}=1 ; \mathrm{V}_{0}=4$ (in units of J), implying $K={ }_{\mathrm{D}}=0=\mathrm{V}=\mathrm{V}_{0}$. Far aw ay from the resonance $T \quad 1, Q \quad P j 1$ and $k j 1, y i e l d i n g$ the two-slit-like form $T A+B \cos$, dom inated by its rst harm onic, w ith $\left.B=A \quad 2 \mathbb{K}^{1} \quad \mathrm{P}\right]$. H ow ever, close the the resonance $T$ show s rich structure; the denom inator in Eq. (16) generates higher harm onics, and the two-slit form ula is com pletely $w$ rong. $T$ his rich structure $m$ ay be $m$ issed if one neglects parts of the -dependence of , as done in parts of Ref. [42]. N ote also the Fano vanishing [36] of $T$ for $V 10$ at $=2 n$, with integer $n$. W ithout interactions, we can repeat this calculation for a dot with several resonances, using Eq. (7). TheRHS frame in F ig. 7 show s results for tw o resonances, with $\mathrm{D}=5$. Interestingly, Fig .7 is qualitatively sim ilar to the experim entally $m$ easured transm ission in $R$ ef. [43]. H ow ever, so far there has been no quantitative analysis of the experim ental data.

To treat the general case, we need inform ation on int. First of all, we em phasize that a successful $t$ to Eq. (16) justi es the neglect of the -dependence of int. If the various procedures to determ ine QD


Figure 7. AB transm ission $T$ versus the AB phase and the gate voltage $V$, for one (LHS) and two (RHS) non-interacting resonances.
from Eq. (16) yield the sam eV-dependence, this would also con $m$ that int is negligibly sm all. A failure of this check, or a $m$ ore com plicated dependence of the $m$ easured $T$ on cos, would imply that int is not negligible.

A s seen from Eq. (14), ext is fully determ ined by a single \visit" of the electron at \ref". For sm all $\mathrm{T}_{\mathrm{B}}$, or large $\mathrm{V}_{0} j=j_{0} j$ it is reasonable to con jecture that int is also dom inated by such processes. In that case, we expect int to be proportionalto the sam e brackets as in Eq. (14), i.e. int $w(z+\infty$ cos ), with a real coe cient $w$. This yields the sam e dependence of $T$ on cos as in Eq. (16), with a shifted coe cient $v$. If $w$ depends only weakly on $V$, then this shift has little e ect on the determ ination of QD. A gain, the validity of this approach relies on getting the sam eV-dependence of $Q D$ from all of its di erent determ inations.

## 4. M odel for the open A B interferom eter

O urm odelfor the open interferom eter is represented schem atically in Fig. 2 (c). In order to obtain explicit expressions, which are easy to calculate, we again neglect interactions, and use a sim ple tight-binding $m$ odel [28]. To allow several leaky branches from each edge of the triangle in $F$ ig. 6, we rst generalize the closed interferom eter $m$ odel, and replace each such edge $s$ by a $1 D$ tight binding $m$ odel of $M_{s}$ sites, $w$ ith $i=0$ and $J_{i ; i+1}=J_{s}(s=` r ; d$ for the left and right upper segm ents and for the low er path, respectively). Taking advantage of gauge invariance, we attach the AB phase factor $e^{i}$ to the hopping am plitude from the right hand \fork" onto its nearest neighbor on branch $r$, which we write as $J_{r} e^{i} . W$ riting the wave functions in segm ent $s$ as $\underset{m}{s}=A_{s}{ }_{s}^{m}+B_{s} s^{m}$, with $s$ given by $E=J_{s}\left(s+s^{1}\right)$, it is easy to express the total transm ission and re ection am plitudes through the interferom eter, $t$ and $r$, in term $s$ of the six am plitudes $f A_{s} ; B_{s} g$, and obtain six linear equations whose coe cients also contain $f S$ x y $g$. Having solved these equations, one nally nds the totaltransm ission amplitude $t$. Interestingly, the dependence of $T$ on
for the closed interferom eter rem ains of the form given in Eq. (16). To obtain the LHS fram e in Fig. 3, we used $M,=M_{r}=6 ; M_{d}=12$, and $J_{s}=J$. A to to . (3) indeed gives that jumpsbetween 0 and , as in Y acoby et al.'s experim ents [8].

W e next proceed to m odel the open interferom eter. P ursuing one possible scenario [27], we m odel the \leaking" from each of the three segm ents on the \ring" (im itating the additional four term inals in the experim ent, Fig. 2 (b)) by connecting each site on the three ring segm ents to a 1D lead, which allow s only an outgoing current to an absorbing reservoir ( F ig. 2 (c)). E ach such segm ent is thus replaced by a \com b" of absorbing \teeth".

W e start by investigating the properties of a single \com b". The \base" of the \com b" is described by
a chain of $M$ tight-binding sites, $w$ ith $J_{m} m+1=J_{c}$ and $m=0$. Each \tooth" is represented by a 1D tight-binding chain, with $j=0$. The rst bond on the \tooth" has $J_{m} ; 0=J_{x}$, while $J_{j ; j+1}=J$ for $j 0$. A ssum ing only outgoing waves on the teeth, w th w ave functions $\mathrm{t}_{x} \mathrm{e}^{\mathrm{ikaj}}$ and energy $\mathrm{E}=2 \mathrm{~J}$ coska, one can elim inate the \teeth" from the equations. The wave functions on the \base" of the com $b$ are then given by ${ }_{m}^{c}=A_{c}{ }_{c}^{m}+B_{c}{ }_{c}^{m}$, where $c$ is a solution of the (com plex energy) equation $E+J_{x}^{2} e^{i k a}=J=J_{c}\left(c^{+}+c_{c}^{1}\right)$. W hen this \comb" is treated as our basic scatterer, i.e. connected via $J_{\text {in }}$ and $J_{\text {out }}$ to our \standard" two leads, then the transm ission and re ection am plitudes via the \com b" are given (up to unim portant phases) by $t=J_{\text {out }}\left(A_{c}{ }_{c}^{N}+B_{c}={ }_{c}^{N}\right)=J$ and $r=J_{\text {in }}\left(A_{c} c+B_{c}={ }_{c}\right)=J \quad e^{\text {jka }}$, and one ends up with two linear equations for $A_{c}$ and $B_{c}$. The results for $T=f j^{f}$ and $R=j j^{\jmath}$ are show $n$, for three values of $M$, in $F$ ig. 8 , as functions of ka $2[0 ;]$ in the free electron energy band, for $J_{x}=: 7 J$ (left), and as functions of $J_{x}$, for $\mathrm{ka}==2$ (right). In the gure, $J_{C}=J_{\text {in }}=J_{\text {out }}=J$. It is rew arding to observe that both $T$ and $R$ are alm ost independent of the electron energy E over a broad range near the band center. It is also interesting to note that for these param eters, $T$ decreases $w$ ith $J_{x}$, but $R$ increases $w$ ith $J_{x}$. For xed $J_{x}, T$ and $R$ exhibit som e even-odd oscillations w th M , but basically $T$ decreases $w$ ith $M$ while $R$ increases tow ards an alm ost constant value for $M>6$. This is understandable: a strong coupling to the \teeth" causes a strong decay of the wave function along the \comb". Thus, for each value of $M$ one can nd an interm ediate optim al region in which both $T$ and $R$ are $s m$ all. $T$ his region broadens, and has sm aller $T$ and $R$, for larger $M$.





$F$ igure 8. Transm ission (thick line) and re ection (thin line) through a $\backslash$ comb", versus ka at $J_{x}=: 7 J$ (left) and versus $J_{x}$ at $k a==2$ (right). The num ber on each fram e gives the num ber of $\backslash$ teeth $", M$.

We next place three such \com bs" on the AB interferom eter, as in Fig. 2 (c), and study the AB trans$m$ ission $T$ as function of the various param eters (for the present punposes, the site \ref" is just equivalent to the other sites on the low er edge, i.e. $0=0$ ). For sim plicity, we set the sam e param eters for all the com bs, and vary the coupling strength $J_{x}$. Since each \tooth" of the \com b" can be replaced by adding the com plex num ber $J_{x}^{2} e^{i k a}=J$ to the energy $E$ in the equations for ${ }_{m}^{s}$ on the ring segm ents, the $m$ athem atics is sim ilar of that of the \bare" closed interferom eter. The main di erence in the results is that now $c$ is com plex, yielding a decay of the wave function through each comb. This also tums the ratio K com plex, so that the num erator in Eq. (16) m ust be replaced by $\mathfrak{j}+\mathrm{K} \mathrm{e}^{i}$ f, yielding non-trivial values for . To dem onstrate qualitative results, we again choose $M, ~=M_{r}=6 ; M_{d}=12$, use $J_{V}=J_{r}=J_{d}=J_{C}=J$ and keep ka $=2$ and the QD param eters $J_{L}(n)=J_{R}(n)=J ; N=4 ; U=20 J$. The choice for the loomb" param eters ensures that $A$ and $B$ in Eq. (3) are of the sam e order. O ther choices give sim ilar qualitative results. Figure 3 show $s$ results for $A$; $B$; $C$ and as function of $V$, for several values of $J_{x}$. $C$ learly, $J_{x}=: 15 J$ gives a phase which is interm ediate between the O nsager jum ps of the left Fig. 3 and the exact intrinsic Qd of

Fig. 1. Increasing $J_{x}$ yields a saturation of onto $Q D$, which persists for a broad range between $J_{x}=: 5 J$ and $J_{x}=: 9 J$. H ow ever, larger values of $J_{x}$, e.g. $J_{x}=1: 5 \mathrm{~J}$, cause a deviation of from $Q D$, due to the increase of the re ection from each \comb". Interestingly, this deviation is in the sam e direction as for sm all $J_{x}$ ! The reason for this is clear: as the re ection of each comb increases, the electron \rattles" in and out of the $Q D$. This localizes it on the $Q D$, and reduces the width of the $Q D$ resonances. For these large values of $J_{x}$, one has fil 1 in Eq. (16). Thus, the two-slit conditions hold, and one has B/ $\mathrm{f}_{-1} j$ and
$=\quad$. W e have solved the equations for the transm ission through the upper branch only (disconnecting the low er branch altogether), and found that indeed, the coe cient $c$ in $t_{1}=c t_{Q D}$ is a constant as long as the re ection of the com bs is sm all. $H$ ow ever, as $J_{x}$ increases above about :9J, C is no longer a constant. The narrow er resonances show $n$ in $F$ ig. 3 (right) fully agree with this $m$ odi ed upper branch transm ission. In any case, \optim al combs", with sm all $T$ and $R$, do yield $=Q D$.

So far, we assum ed no direct losses from the Q $D$ itself. It is easy to add such losses, by connecting a $\backslash$ lossy" channel to each resonant state n [27], sim ilar to the \teeth" of our $\backslash$ com bs", w ith a tunneling am plitude $J_{x}^{0}$. A s before, th is introduces a com plex addition $J_{x}^{\infty} e^{\text {ika }}$ to $E \quad E_{R}(n)$. Figure 9 show $s$ the results for the sam $e$ param eters as above, but w ith $J_{x}=J_{x}^{0}=: 9 J$. C learly, the new in aginary parts elim inate the Fano-like zero in B, and yield a sm ooth variation of near the \intrinsic phase lapses". A though sim ilar to the behavior arising in the BW approxim ation, the present e ects are real, due to physicalbreaking of the unitarity on the $Q D$. It is interesting to note that the data of Ref. [9] show sim ilar (and otherw ise unexplained) mm ooth features. It is how ever possible that the latter come from nite tem perature averaging [34].


Figure 9. Sam e as Fig. 3, but with a \lossy" channelattached to the Q D ; $J_{x}=J_{x}^{0}=: 9 \mathrm{~J}$.

## 5. C oncluding rem arks

$B$ asically, we presented three $m$ ethods to $m$ easure the intrinsic scattering phase of a quantum dot. T he rst $m$ ethod is based on Eq. (6), and does not involve interferom etry. The second is based on Eq. (15), which allow s one to extract inform ation from $m$ easurem ents on the closed ABI. The third m ethod uses the open A B I, but requires conditions under which this A B I behaves as a tw o-slit interferom eter. A s stated, a
convincing approach would be to use $m$ ore than one $m$ ethod, $w$ ith the sam $E Q D$, and to obtain consistent results.

The actualplots show $n$ in this paperw ere obtained $w$ ith sim ple tight-binding $m$ odels, $w$ ithout interactions (except for sim ple $H$ artree-like term $s$ in the single electron energy). T herefore, these plots cannot be used for the strongly interacting case, particularly in the $K$ ondo regim $e$. A though som e aspects of the interacting case have been included in our analysis for the single Q D or for the closed AB I, the fiull inclusion of interactions in practical calculations rem ain an open problem.

In addition to electron-electron interactions, onem ight also consider the e ects of other interactions. We have recently studied the interactions of the electrons with a phonon bath, which acts only on the Q D (still em bedded on one path of the closed ABI). The persistent current $I_{p}$ around the \ring", at steady state, is found to be enhanced in an appropriate range of the intensity of the acoustic source [44].

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